NSN 5961-00-539-6413

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-539-6413 **Inclosure Material:** Metal **Overall Length:** 0.370 inches **Terminal Length:** 1.125 inches **Overall Diameter:** 0.230 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 47.0 reverse voltage, peak **Current Rating Per Characteristic:** 0.10 microamperes forward current, average peak **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release1348b professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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